

HIGH SPEED 8K x 8 CMOS PROM/RPROM

KEY FEATURES

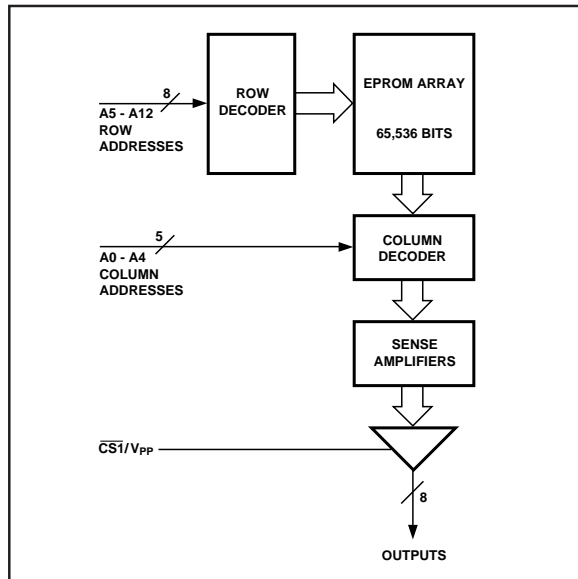
- **Ultra-Fast Access Time**
 - $t_{ACC} = 25 \text{ ns}$
 - $t_{CS} = 12 \text{ ns}$
- **Low Power Consumption**
- **Fast Programming**
- **Pin Compatible with Bipolar PROMs**
- **Immune to Latch-UP**
 - Up to 200 mA
- **ESD Protection Exceeds 2000 V**
- **Available in 300 Mil DIP and PLDCC**

GENERAL DESCRIPTION

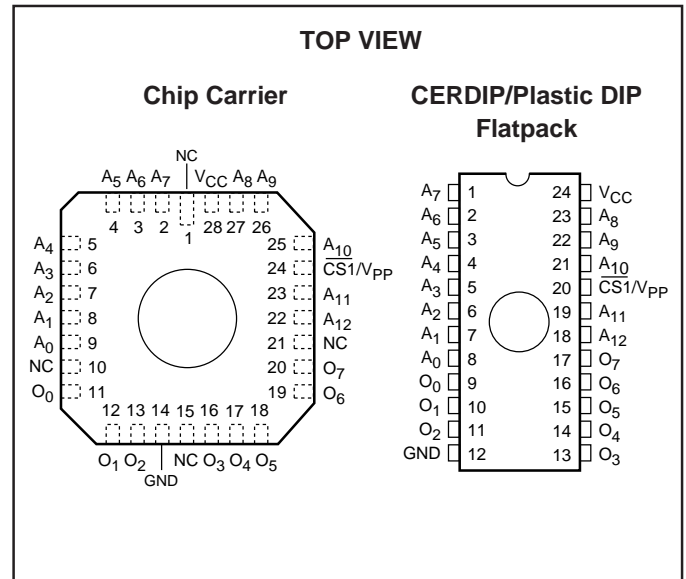
The WS57C49C is a High Performance 64K UV Erasable Electrically Re-Programmable Read Only Memory (RPROM). It is manufactured in an advanced CMOS technology which enables it to operate at Bipolar PROM speeds while consuming only 25% of the power required by its Bipolar counterparts. A further advantage of the WS57C49C over Bipolar PROM devices is the fact that it utilizes a proven EPROM technology. This enables the entire memory array to be tested for switching characteristics and functionality after assembly. Unlike devices which cannot be erased, every WS57C49C in a windowed package is 100% tested with worst case test patterns both before and after assembly.

The WS57C49C is configured in the standard Bipolar PROM pinout which provides an easy upgrade path for systems which are currently using Bipolar PROMs, or its predecessor, the WS57C49B.

BLOCK DIAGRAM



PIN CONFIGURATION



PRODUCT SELECTION GUIDE

| PARAMETER | 57C49C-25 | 57C49C-35 | 57C49C-45 | 57C49C-55 | 57C49C-70 |
|-------------------------------|-----------|-----------|-----------|-----------|-----------|
| Address Access Time (Max) | 25 ns | 35 ns | 45 ns | 55 ns | 70 ns |
| CS to Output Valid Time (Max) | 12 ns | 20 ns | 25 ns | 25 ns | 25 ns |

ABSOLUTE MAXIMUM RATINGS*

Storage Temperature.....-65° to + 150°C
 Voltage on any Pin with
 Respect to Ground-0.6V to +7V
 V_{PP} with Respect to Ground.....-0.6V to + 13V
 ESD Protection.....>2000V

***NOTICE:**

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods of time may affect device reliability.

MODE SELECTION

| MODE \ PINS | $\overline{CS1}/V_{PP}$ | V_{CC} | OUTPUTS |
|---------------------------|-------------------------|----------|----------------|
| Read | V_{IL} | V_{CC} | D_{OUT} |
| Output Disable | V_{IH} | V_{CC} | High Z |
| Program | V_{PP} | V_{CC} | D_{IN} |
| Program Verify | V_{IL} | V_{CC} | D_{OUT} |

OPERATING RANGE

| RANGE | TEMPERATURE | V_{CC} |
|--------------|--------------------|----------------------------|
| Commercial | 0°C to +70°C | +5V ± 10% |
| Industrial | -40°C to +85°C | +5V ± 10% |
| Military | -55°C to +125°C | +5V ± 10% |

DC READ CHARACTERISTICS Over Operating Range. (See Above)

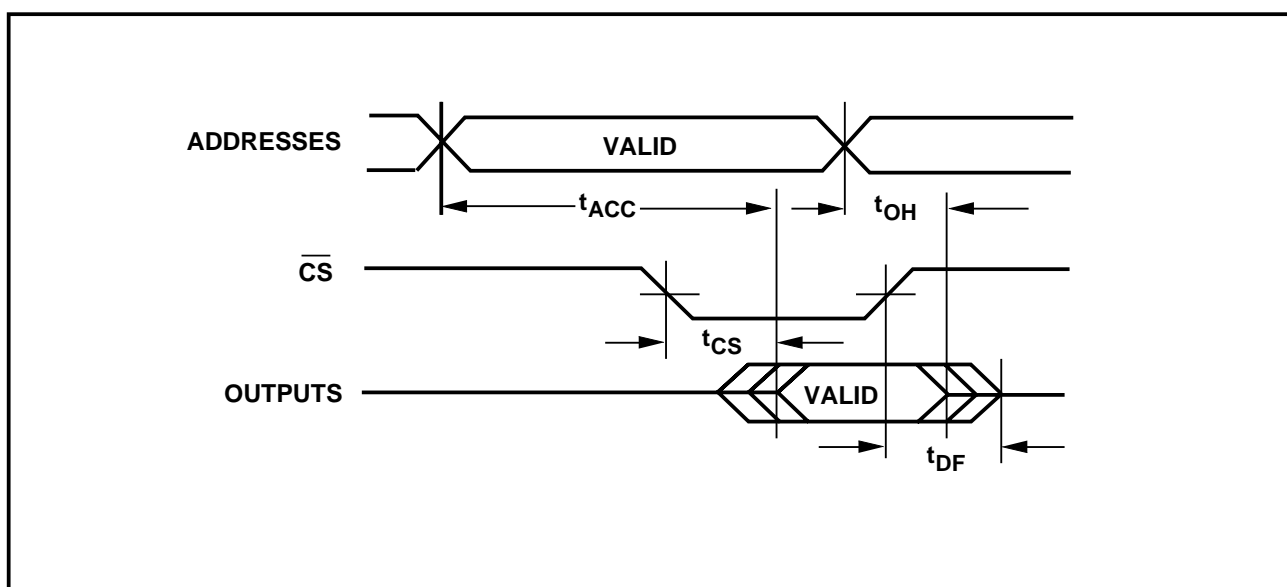
| SYMBOL | PARAMETER | TEST CONDITIONS | MIN | MAX | UNITS |
|---------------|--------------------------------|---|------------|----------------|--------------|
| V_{IL} | Input Low Voltage | (Note 3) | -0.1 | 0.8 | V |
| V_{IH} | Input High Voltage | (Note 3) | 2.0 | $V_{CC} + 0.3$ | V |
| V_{OL} | Output Low Voltage | $I_{OL} = 16$ mA | | 0.4 | V |
| V_{OH} | Output High Voltage | $I_{OH} = -4$ mA | 2.4 | | V |
| I_{CC1} | V_{CC} Active Current (CMOS) | $V_{CC} = 5.5$ V, $f = 0$ MHz (Note 1), Output Not Loaded Add 3 mA/MHz for AC Operation | Comm'l | 30 | mA |
| | | | Industrial | 35 | mA |
| | | | Military | 35 | mA |
| I_{CC2} | V_{CC} Active Current (TTL) | $V_{CC} = 5.5$ V, $f = 0$ MHz (Note 2), Output Not Loaded Add 3 mA/MHz for AC Operation | Comm'l | 40 | mA |
| | | | Industrial | 50 | mA |
| | | | Military | 50 | mA |
| I_{LI} | Input Leakage Current | $V_{IN} = 5.5$ V or Gnd | -10 | 10 | μ A |
| I_{LO} | Output Leakage Current | $V_{OUT} = 5.5$ V or Gnd | -10 | 10 | μ A |

- NOTES:**
1. CMOS inputs: GND ± 0.3V or $V_{CC} \pm 0.3$ V.
 2. TTL inputs: $V_{IL} \leq 0.8$ V, $V_{IH} \geq 2.0$ V.
 3. These are absolute voltages with respect to device ground pin and include all overshoots due to system and/or tester noise. Do not attempt to test these values without suitable equipment.

AC READ CHARACTERISTICS Over Operating Range. (See Above)

| PARAMETER | SYMBOL | 57C49C-25 | | 57C49C-35 | | 57C49C-45 | | 57C49C-55 | | 57C49C-70 | | UNITS |
|----------------------------------|-----------|-----------|-----|-----------|-----|-----------|-----|-----------|-----|-----------|-----|-------|
| | | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | MIN | MAX | |
| Address to Output Delay | t_{ACC} | | 25 | | 35 | | 45 | | 55 | | 70 | ns |
| $\overline{CS1}$ to Output Delay | t_{CS} | | 12 | | 20 | | 25 | | 25 | | 25 | |
| Output Disable to Output Float* | t_{DF} | | 12 | | 25 | | 25 | | 25 | | 25 | |
| Address to Output Hold | t_{OH} | 0 | | 0 | | 0 | | 0 | | 0 | | |

*Sampled, Not 100% Tested.

AC READ TIMING DIAGRAM

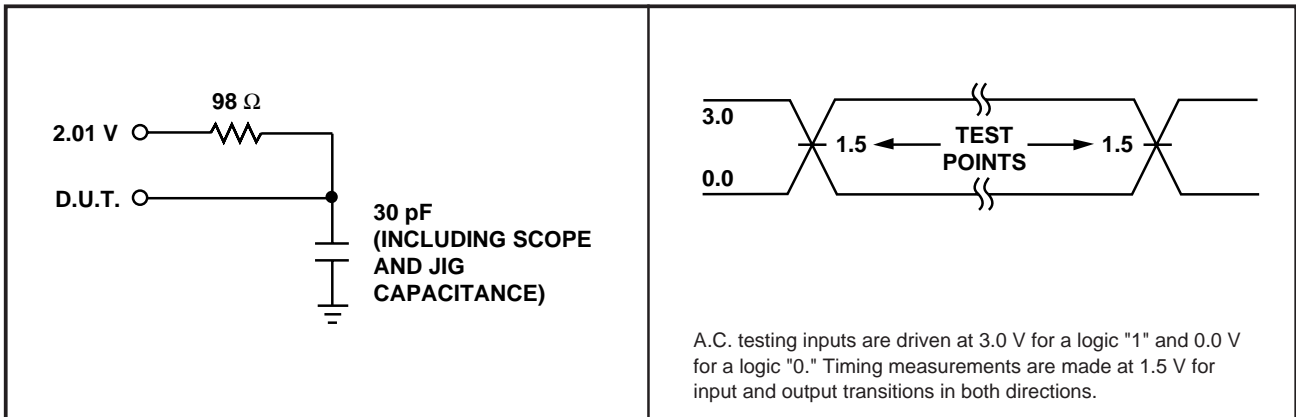
CAPACITANCE⁽⁴⁾ $T_A = 25^\circ\text{C}$, $f = 1\text{ MHz}$

| SYMBOL | PARAMETER | CONDITIONS | TYP ⁽⁵⁾ | MAX | UNITS |
|-----------|----------------------|-----------------------|--------------------|-----|-------|
| C_{IN} | Input Capacitance | $V_{IN} = 0\text{V}$ | 4 | 6 | pF |
| C_{OUT} | Output Capacitance | $V_{OUT} = 0\text{V}$ | 8 | 12 | pF |
| C_{VPP} | V_{PP} Capacitance | $V_{PP} = 0\text{V}$ | 18 | 25 | pF |

NOTES: 4. This parameter is only sampled and is not 100% tested.
 5. Typical values are for $T_A = 25^\circ\text{C}$ and nominal supply voltages.

TEST LOAD (High Impedance Test Systems)

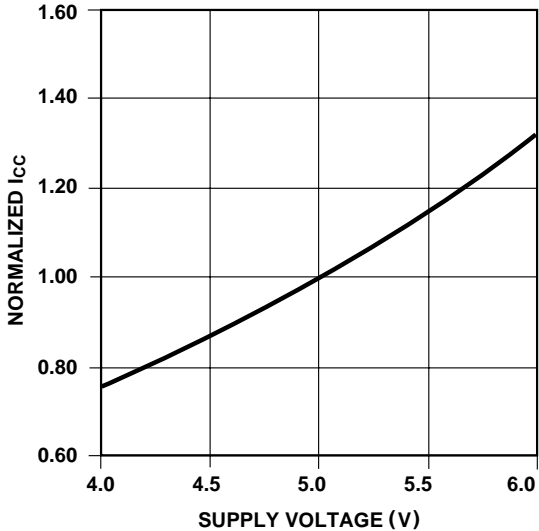
A.C. TESTING INPUT/OUTPUT WAVEFORM



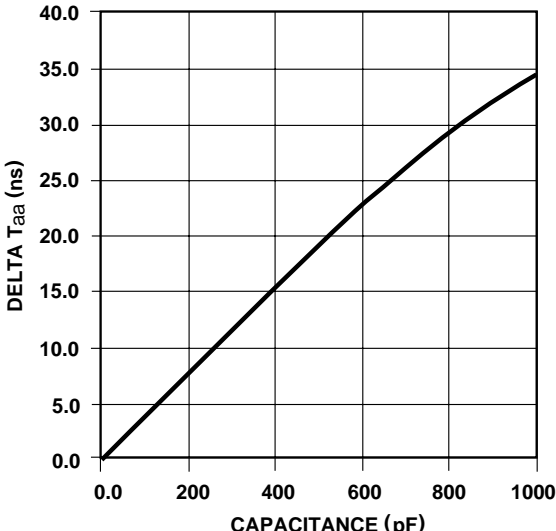
NOTE: 6. Provide adequate decoupling capacitance as close as possible to this device to achieve the published A.C. and D.C. parameters. A 0.1 microfarad capacitor in parallel with a 0.01 microfarad capacitor connected between V_{CC} and ground is recommended. Inadequate decoupling may result in access time degradation or other transient performance failures.



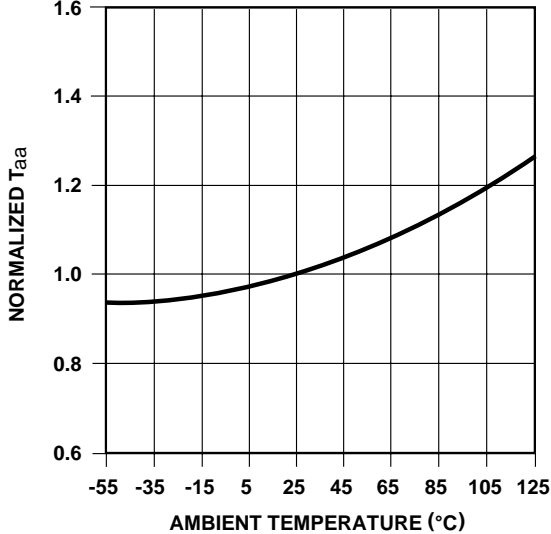
**NORMALIZED SUPPLY CURRENT
vs.
SUPPLY VOLTAGE**



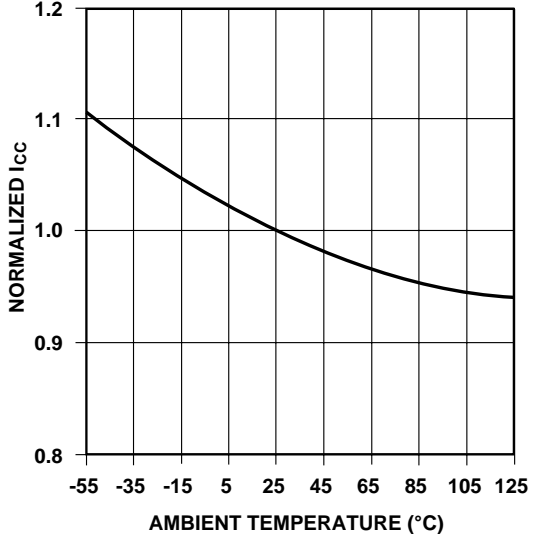
**TYPICAL ACCESS TIME CHANGE
vs.
OUTPUT LOADING**



**NORMALIZED T_{aa}
vs.
AMBIENT TEMPERATURE**



**NORMALIZED SUPPLY CURRENT
vs.
AMBIENT TEMPERATURE**



PROGRAMMING INFORMATION

DC CHARACTERISTICS ($T_A = 25 \pm 5^\circ\text{C}$, $V_{CC} = 6.25 \text{ V} \pm 0.25 \text{ V}$, $V_{PP} = 12.75 \pm 0.25 \text{ V}$)

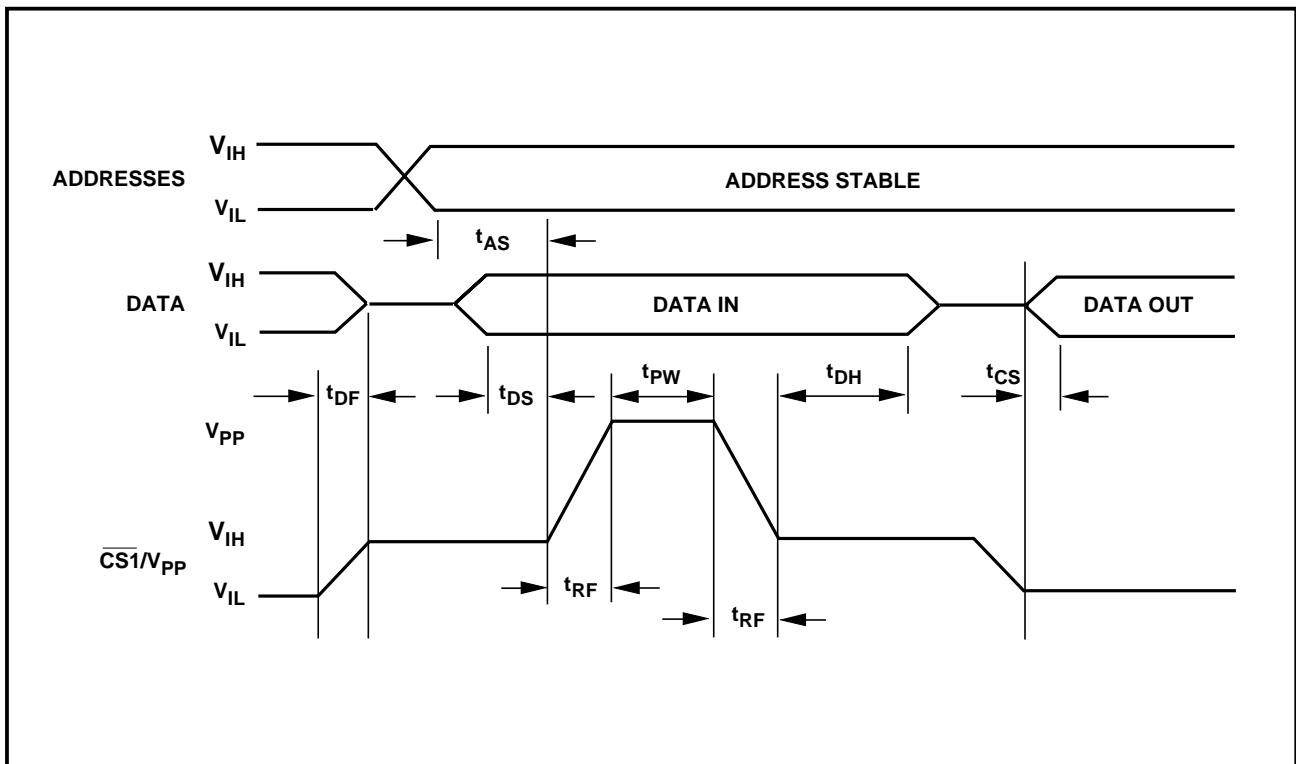
| SYMBOLS | PARAMETER | MIN | MAX | UNITS |
|----------|---|-----|------|---------------|
| I_{LI} | Input Leakage Current ($V_{IN} = V_{CC}$ or Gnd) | -10 | 10 | μA |
| I_{PP} | V_{PP} Supply Current During Programming Pulse | | 60 | mA |
| I_{CC} | V_{CC} Supply Current | | 35 | mA |
| V_{OL} | Output Low Voltage During Verify ($I_{OL} = 16 \text{ mA}$) | | 0.45 | V |
| V_{OH} | Output High Voltage During Verify ($I_{OH} = -4 \text{ mA}$) | 2.4 | | V |

NOTES: 7. V_{PP} must not be greater than 13 volts including overshoot.

AC CHARACTERISTICS ($T_A = 25 \pm 5^\circ\text{C}$, $V_{CC} = 6.25 \text{ V} \pm 0.25 \text{ V}$, $V_{PP} = 12.75 \pm 0.25 \text{ V}$)

| SYMBOLS | PARAMETER | MIN | TYP | MAX | UNITS |
|----------|-----------------------------|-----|-----|-----|---------------|
| t_{AS} | Address Setup Time | 2 | | | μs |
| t_{DF} | Chip Disable Setup Time | | | 30 | ns |
| t_{DS} | Data Setup Time | 2 | | | μs |
| t_{PW} | Program Pulse Width | 100 | | 200 | μs |
| t_{DH} | Data Hold Time | 2 | | | μs |
| t_{CS} | Chip Select Delay | | | 30 | ns |
| t_{RF} | V_{PP} Rise and Fall Time | 1 | | | μs |

PROGRAMMING WAVEFORM



ORDERING INFORMATION

| PART NUMBER | SPEED (ns) | PACKAGE TYPE | PACKAGE DRAWING | OPERATING TEMPERATURE RANGE | WSI MANUFACTURING PROCEDURE |
|-----------------|------------|--------------------------|-----------------|-----------------------------|-----------------------------|
| WS57C49C-25D | 25 | 24 Pin CERDIP, 0.6" | D1 | Comm'l | Standard |
| WS57C49C-25J | 25 | 28 Pin PLDCC | J3 | Comm'l | Standard |
| WS57C49C-25S | 25 | 24 Pin Plastic DIP, 0.3" | S1 | Comm'l | Standard |
| WS57C49C-25T | 25 | 24 Pin CERDIP, 0.3" | T1 | Comm'l | Standard |
| WS57C49C-35CMB | 35 | 28 Pad CLLCC | C1 | Military | MIL-STD-883C |
| WS57C49C-35D | 35 | 24 Pin CERDIP, 0.6" | D1 | Comm'l | Standard |
| WS57C49C-35DMB | 35 | 24 Pin CERDIP, 0.6" | D1 | Military | MIL-STD-883C |
| WS57C49C-35J | 35 | 28 Pin PLDCC | J3 | Comm'l | Standard |
| WS57C49C-35L | 35 | 28 Pin CLDCC | L2 | Comm'l | Standard |
| WS57C49C-35S | 35 | 24 Pin Plastic DIP, 0.3" | S1 | Comm'l | Standard |
| WS57C49C-35T | 35 | 24 Pin CERDIP, 0.3" | T1 | Comm'l | Standard |
| WS57C49C-35TI | 35 | 24 Pin CERDIP, 0.3" | T1 | Industrial | Standard |
| WS57C49C-35TMB | 35 | 24 Pin CERDIP, 0.3" | T1 | Military | MIL-STD-883C |
| WS57C49C-45CMB* | 45 | 28 Pad CLLCC | C1 | Military | MIL-STD-883C |
| WS57C49C-45D | 45 | 24 Pin CERDIP, 0.6" | D1 | Comm'l | Standard |
| WS57C49C-45DMB* | 45 | 24 Pin CERDIP, 0.6" | D1 | Military | MIL-STD-883C |
| WS57C49C-45J | 45 | 28 Pin PLDCC | J3 | Comm'l | Standard |
| WS57C49C-45JI | 45 | 28 Pin PLDCC | J3 | Industrial | Standard |
| WS57C49C-45L | 45 | 28 Pin CLDCC | L2 | Comm'l | Standard |
| WS57C49C-45S | 45 | 24 Pin Plastic DIP, 0.3" | S1 | Comm'l | Standard |
| WS57C49C-45T | 45 | 24 Pin CERDIP, 0.3" | T1 | Comm'l | Standard |
| WS57C49C-45TI | 45 | 24 Pin CERDIP, 0.3" | T1 | Industrial | Standard |
| WS57C49C-45TMB* | 45 | 24 Pin CERDIP, 0.3" | T1 | Military | MIL-STD-883C |
| WS57C49C-55CMB* | 55 | 28 Pad CLLCC | C1 | Military | MIL-STD-883C |
| WS57C49C-55D | 55 | 24 Pin CERDIP, 0.6" | D1 | Comm'l | Standard |
| WS57C49C-55DMB* | 55 | 24 Pin CERDIP, 0.6" | D1 | Military | MIL-STD-883C |
| WS57C49C-55FMB* | 55 | 24 Pin Ceramic Flatpack | F1 | Military | MIL-STD-883C |
| WS57C49C-55J | 55 | 28 Pin PLDCC | J3 | Comm'l | Standard |
| WS57C49C-55T | 55 | 24 Pin CERDIP, 0.3" | T1 | Comm'l | Standard |
| WS57C49C-55TMB* | 55 | 24 Pin CERDIP, 0.3" | T1 | Military | MIL-STD-883C |
| WS57C49C-70CMB* | 70 | 28 Pad CLLCC | C1 | Military | MIL-STD-883C |
| WS57C49C-70D | 70 | 24 Pin CERDIP, 0.6" | D1 | Comm'l | Standard |
| WS57C49C-70TMB* | 70 | 28 Pin CERDIP, 0.3" | T1 | Military | MIL-STD-883C |

NOTE: The actual part marking will not include the initials "WS."

*SMD product. See section 4 for SMD number.

PROGRAMMING/ALGORITHMS/ERASURE/PROGRAMMERS

**REFER TO
PAGE 5-1**

The WS57C49C is programmed using Algorithm D shown on page 5-9.



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